THE DATASHEET OF

TB2600M-13-F

www.win-source.net 0086-755-83957316

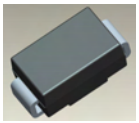
50A BIDIRECTIONAL SURFACE MOUNT THYRISTOR SURGE PROTECTION DEVICE

Features

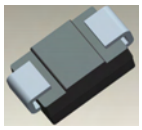
- 50A Peak Pulse Current @ 10/1000μs
- 250A Peak Pulse Current @ 8/20μs
- 58 - 320V Stand-Off Voltages
- Oxide-Glass Passivated Junction
- Bidirectional Protection In a Single Device
- High Off-State impedance and Low On-State Voltage
- Helps Equipment Meet GR-1089-CORE, IEC 61000-4-5, FCC Part 68, ITU-T K.20/K.21, and UL497B
- UL Listed Under Recognized Component Index, File Number 156346
- **Lead Free Finish/RoHS Compliant (Note 1)**
- **Green Molding Compound (No Halogen and Antimony) (Note 2)**

Mechanical Data

- Case: SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208
- Polarity: None; Bidirectional Devices Have No Polarity Indicator
- Weight: 0.093 grams (approximate)



Top View



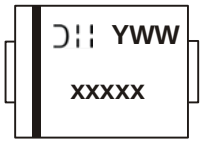
Bottom View

Ordering Information (Note 3)

Part Number	Case	Packaging
TB0640M-13-F	SMB	3000/Tape & Reel
TB0720M-13-F	SMB	3000/Tape & Reel
TB0900M-13-F	SMB	3000/Tape & Reel
TB1100M-13-F	SMB	3000/Tape & Reel
TB1300M-13-F	SMB	3000/Tape & Reel
TB1500M-13-F	SMB	3000/Tape & Reel
TB1800M-13-F	SMB	3000/Tape & Reel
TB2300M-13-F	SMB	3000/Tape & Reel
TB2600M-13-F	SMB	3000/Tape & Reel
TB3100M-13-F	SMB	3000/Tape & Reel
TB3500M-13-F	SMB	3000/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



xxxxx = Product type marking code
(See Electrical Characteristics table on page 3)
= Manufacturers' code marking
YWW = Date code marking
Y = Last digit of year (ex: 2 for 2002)
WW = Week code (01 to 53)

© Diodes Incorporated

Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

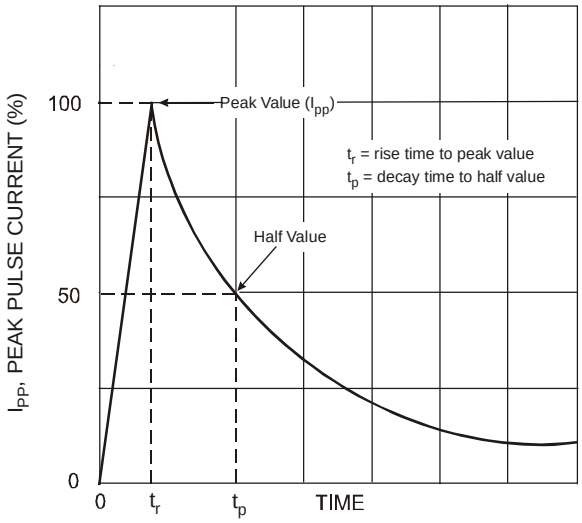
Characteristic		Symbol	Value	Unit
Non-Repetitive Peak Impulse Current	@10/1000us	I_{pp}	50	A
Non-Repetitive Peak On-State Current	@8.3ms (one-half cycle)	I_{TSM}	30	A
Typical Positive Temperature Coefficient for Breakdown Voltage		$\Delta VBR/\Delta T_j$	0.1	%/°C

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Lead	$R_{\theta JL}$	20	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	100	°C/W
Junction Temperature Range	T_J	-40 to +150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

Maximum Rated Surge Waveform

Waveform	Standard	Ipp (A)
2/10 us	GR-1089-CORE	300
8/20 us	IEC 61000-4-5	250
10/160 us	FCC Part 68	150
10/700 us	ITU-T, K.20/K.21	100
10/560 us	FCC Part 68	75
10/1000 us	GR-1089-CORE	50



© Diodes Incorporated

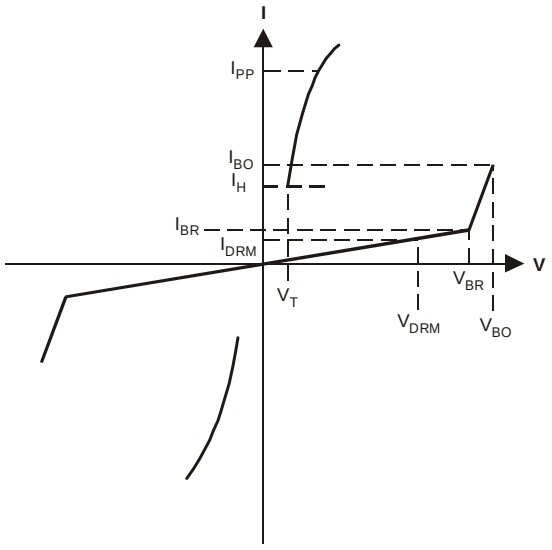
Electrical Characteristics @T_A = 25°C unless otherwise specified

Part Number	Maximum Rated Repetitive Off-State Voltage	Maximum Off-State Leakage Current @ V_{DRM}	Maximum Breakover Voltage	Maximum On-State Voltage @ I_T = 1A	Breakover Current I_{BO}		Holding Current I_H		Typical Off-State Capacitance	Marking Code
	V_{DRM} (V)	I_{DRM} (uA)	V_{BO} (V)	V_T (V)	Min (mA)	Max (mA)	Min (mA)	Max (mA)	C_O (pF)	
TB0640M	58	5	77	3.5	50	800	150	800	140	T064M
TB0720M	65	5	88	3.5	50	800	150	800	140	T072M
TB0900M	75	5	98	3.5	50	800	150	800	140	T090M
TB1100M	90	5	130	3.5	50	800	150	800	90	T110M
TB1300M	120	5	160	3.5	50	800	150	800	90	T130M
TB1500M	140	5	180	3.5	50	800	150	800	90	T150M
TB1800M	160	5	220	3.5	50	800	150	800	90	T180M
TB2300M	190	5	265	3.5	50	800	150	800	60	T230M
TB2600M	220	5	300	3.5	50	800	150	800	60	T260M
TB3100M	275	5	350	3.5	50	800	150	800	60	T310M
TB3500M	320	5	400	3.5	50	800	150	800	60	T350M

Symbol	Parameter
V_{DRM}	Stand-off Voltage
I_{DRM}	Leakage current at stand-off voltage
V_{BR}	Breakdown voltage
I_{BR}	Breakdown current
V_{BO}	Breakover voltage
I_{BO}	Breakover current
I_H	Holding current Note 4
V_T	On state voltage
I_{PP}	Peak pulse current
C_O	Off-state capacitance Note 5

Notes: 4. $I_H > (V_L/R_L)$ If this criterion is not obeyed, the TSPD triggers but does not return correctly to high-resistance state. The surge recovery time does not exceed 30ms.

5. Off-state capacitance measured at f = 1.0MHz, 1.0V_{RMS} signal, V_R = 2V_{DC} bias.



© Diodes Incorporated

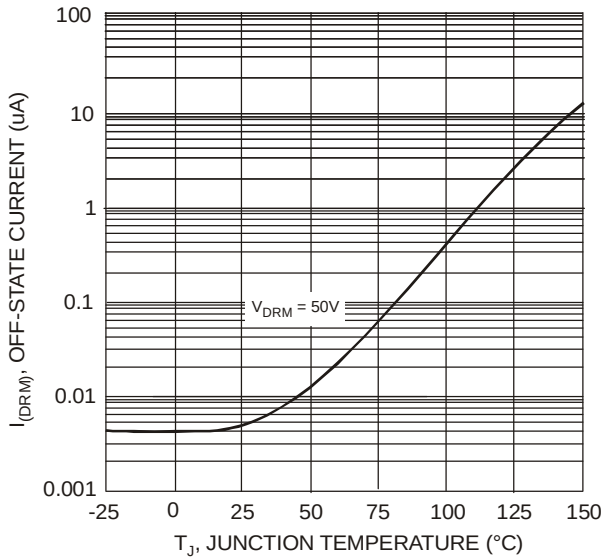


Fig. 1 Off-State Current vs. Junction Temperature

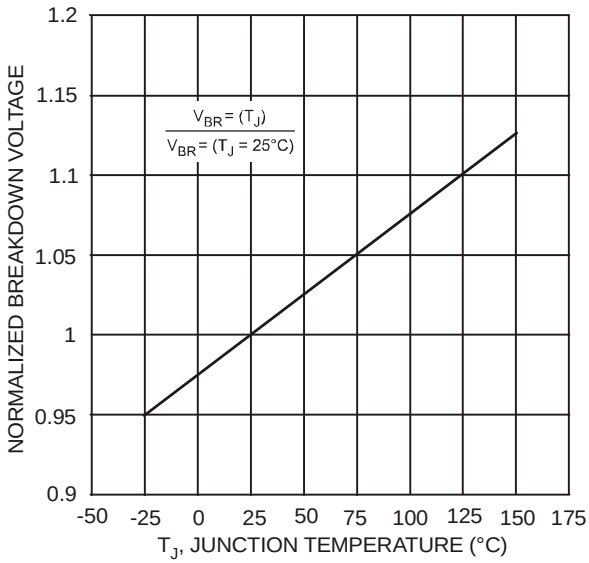


Fig. 2 Relative Variation of Breakdown Voltage vs. Junction Temperature

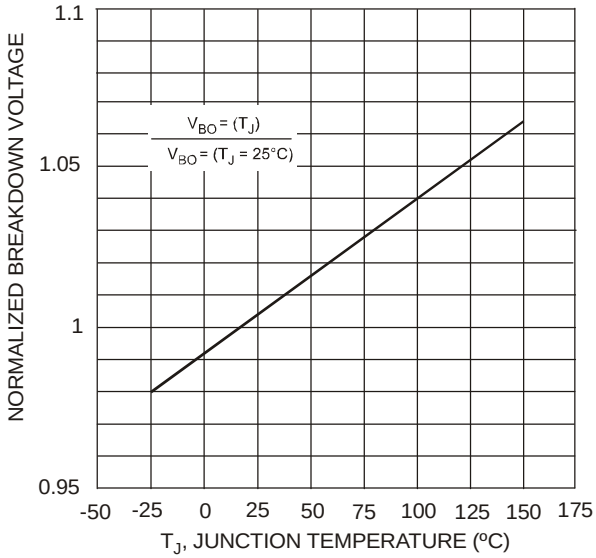


Fig. 3 Relative Variation of Breakover Voltage vs. Junction Temperature

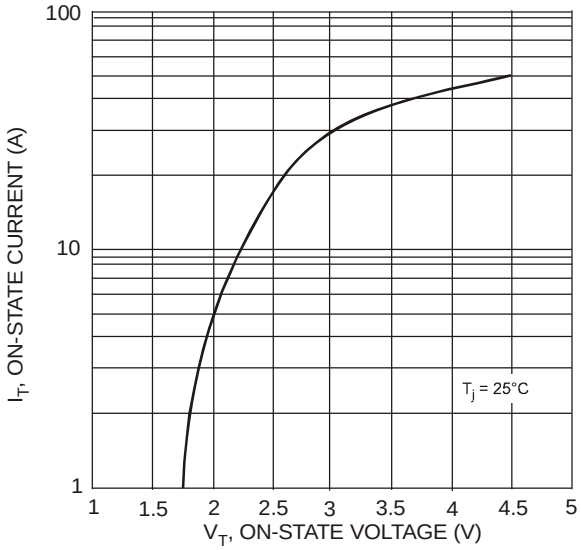


Fig. 4 On-State Current vs. On-State Voltage

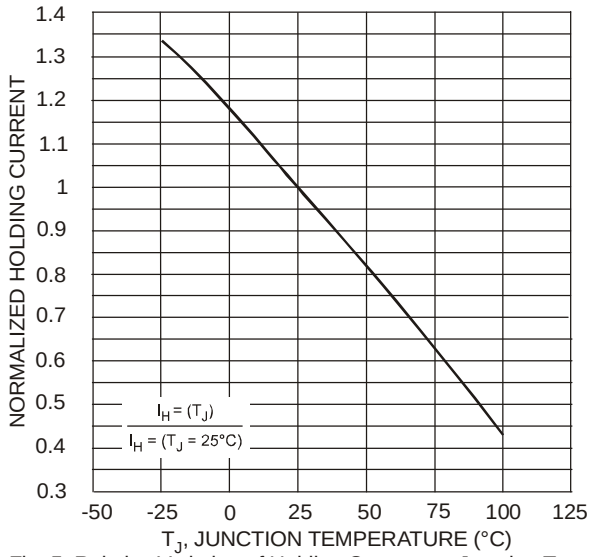


Fig. 5 Relative Variation of Holding Current vs. Junction Temperature

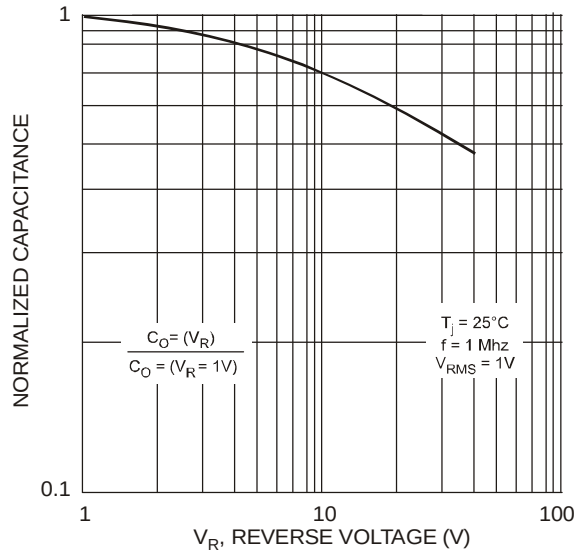
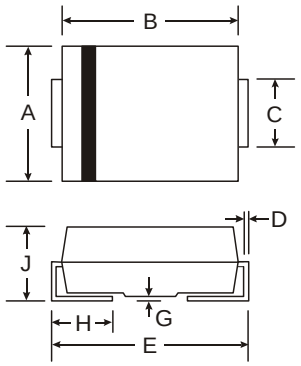


Fig. 6 Relative Variation of Junction Capacitance vs. Reverse Voltage Bias

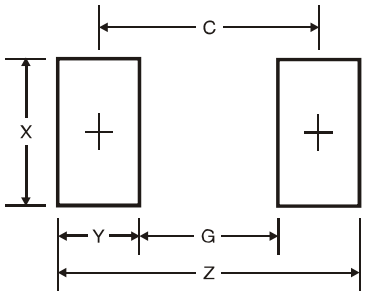
© Diodes Incorporated

Package Outline Dimensions



SMB		
Dim	**Min**	**Max**
A	3.30	3.94
B	4.06	4.57
C	1.96	2.21
D	0.15	0.31
E	5.00	5.59
G	0.05	0.20
H	0.76	1.52
J	2.00	2.50
All Dimensions in mm		

Suggested Pad Layout



SMB Dimensions	Value (in mm)
Z	6.8
G	1.8
X	2.3
Y	2.5
C	4.3

© Diodes Incorporated

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- View TB2600M-13-F on WIN SOURCE
- Diodes Incorporated Information

Optimize Your Supply Chain with WIN SOURCE Solutions

- Global Sourcing Solution
- Obsolete Management
- Cost Control Management
- Shortage Management
- Alternative Solution
- Excess Inventory Management